TOSHIBA LED LAMP GaP GREEN LIGHT EMISSION

TLGD233P

PANEL CIRCUIT INDICATOR

- 2.5×5mm Arch Lens
- All Plastic Mold Type Colorless Clear Lens
- Low Drive Current, High Intensity Green Light Emission Recommended Forward Current: IF=15~20mA (DC)
- All Plastic Molded Lens, Provides an Excellent ON-OFF Contrast Ratio.
- Fast Response Time, Capable of Pulse Operation.
- Application: Level Meter, Automotive Use, Capable of Thin Space for Backlighting
- Without stand-offs

MAXIMUM RATINGS ($Ta = 25^{\circ}C$)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Forward Current (DC)	$I_{\mathbf{F}}$	40	mA	
Reverse Voltage	V_{R}	4	V	
Power Dissipation	$P_{\mathbf{D}}$	125	mW	
Operating Temperature Range	$T_{ m opr}$	-20~75	°C	
Storage Temperature Range	$\mathrm{T_{stg}}$	-30~100	$^{\circ}\mathrm{C}$	

Unit in mm 5.0 ± 0.2 935 8 ଷ ANODE CATHODE **JEDEC**

Weight: 0.23g

TOSHIBA

EIAJ

TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.

The information contained herein is subject to change without notice.

ELECTRO-OPTICAL CHARACTERISTICS (Ta = 25°C)

CHAF	RACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Forward V	oltage	$ m V_{f F}$	$I_{\mathbf{F}} = 20 \text{mA}$	_	2.15	2.8	V
Reverse Cu	ırrent	$I_{ m R}$	$V_R=4V$	_	_	100	μ A
Luminous	TLGD233P	- I _V	I _F =20mA (Note)	153	250	-	
Intensity	TLGD233P (PQ)			153	_	736	mcd
Peak Emis	sion Wave Length	$\lambda_{ m p}$	I _F =20mA	_	567	_	nm
Spectral Li	ine Half Width	Δλ	$I_{ m F}$ = 20mA	_	25	—	nm

(Note) Rank selection carried out under next standard range respectively, although it needs $\pm 15\%$ additionary for guaranteed limits.

P: 180-360mcd Q: 320-640mcd

Each rank products is classified by package unit, and (PQ) includes P and Q.

PRECAUTION

Please be careful of the followings.

- Soldering temperature: 260°C MAX. Soldering time: 3s MAX. (Soldering portion of lead: up to 2mm from the body of the device)
- If the lead is formed, the lead should be formed up to 5mm from the body of the device without forming stress to the resin. Soldering should be performed after lead forming.









